

# ADD-A-PAK Gen 7 Power Modules Schottky Rectifier, 400 A



ADD-A-PAK

PRODUCT SUMMARY				
I <sub>F(AV)</sub>	400 A			
V <sub>R</sub>	45 V			
Package	ADD-A-PAK Gen 7			
Circuit	Two diodes common cathode			

#### **MECHANICAL DESCRIPTION**

The ADD-A-PAK Gen 7, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

#### **FEATURES**

- 175 °C T<sub>J</sub> operation
- Low forward voltage drop
- High frequency operation
- · Low thermal resistance
- UL approved file E78996
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **BENEFITS**

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- · High surge capability
- · Easy mounting on heatsink

#### **ELECTRICAL DESCRIPTION / APPLICATIONS**

The VS-VSKCS401.. Schottky rectifier common cathode has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I <sub>F(AV)</sub>	Rectangular waveform	400	А			
V <sub>RRM</sub>		45	V			
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	29 000	А			
V <sub>F</sub>	200 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.69	V			
TJ	Range	-55 to +175	°C			

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-VSKCS401/045	UNITS		
Maximum DC reverse voltage	$V_{R}$	45	V		
Maximum working peak reverse voltage	$V_{RWM}$	45	V		



ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average	per module		I <sub>F(AV)</sub> 50 % duty cycle at T <sub>C</sub> = 120 °C, rectangular waveform		400	
forward current	per leg	IF(AV)			200	
Maximum peak one cycle		I	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	29 000	Α
non-repetitive surge current		I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse rated V <sub>RRM</sub> applied	3400		
Non-repetitive avalanche energ	у	E <sub>AS</sub>	$T_J = 25  ^{\circ}\text{C},  I_{AS} = 24  \text{A},  L = 1  \text{mH}$		270	mJ
Repetitive avalanche current		I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		Α	

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
	.,	200 A	T <sub>J</sub> = 25 °C	0.72	V
Maximum forward voltage drop		400 A		0.98	
waximum lorward voltage drop	$V_{FM}$	200 A	T <sub>J</sub> = 125 °C	0.69	
		400 A		0.96	
Maximum reverse leakage current		T <sub>J</sub> = 25 °C	V <sub>R</sub> = Rated V <sub>R</sub>	20	mA
Waxiiiluiii levelse leakage cullelii	I <sub>RM</sub>	T <sub>J</sub> = 125 °C		180	IIIA
Maximum junction capacitance	C <sub>T</sub>	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		10 300	pF
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body		5.0	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs
Maximum RMS insulation voltage	V <sub>INS</sub>	1 50 Hz		3000 (1 min) 3600 (1 s)	V

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C
Maximum thermal resistance, junction to case per leg		R <sub>thJC</sub>	DC operation	0.26	°C/W
Typical thermal resistance, case to heatsink per module		R <sub>thCS</sub>		0.1	C/VV
Approximate weight				75	g
Approximate weight				2.7	oz.
Mounting torque ± 10 %	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of 3 h to allow for the	4	Nm
	busbar		spread of the compound.	3	INIII
Case style	•		JEDEC®	TO-240AA co	ompatible

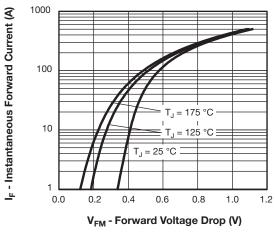


Fig. 1 - Maximum Forward Voltage Drop Characteristics

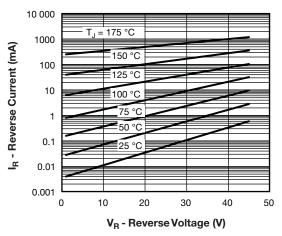


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

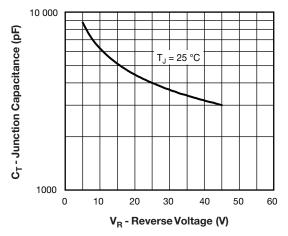


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

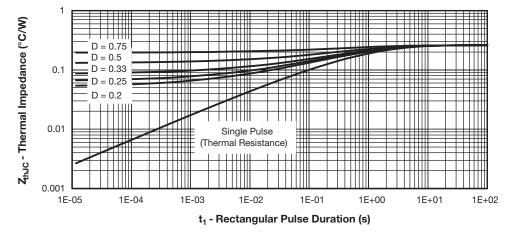


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

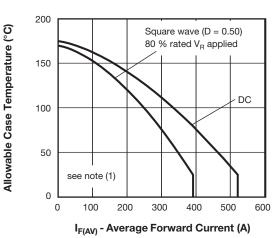


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

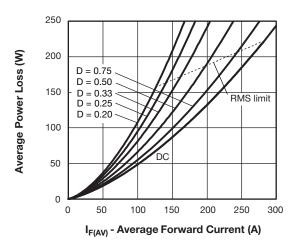


Fig. 6 - Forward Power Loss Characteristics

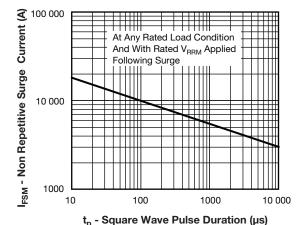


Fig. 7 - Maximum Non-Repetitive Surge Current

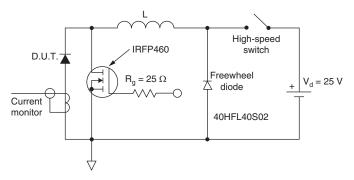


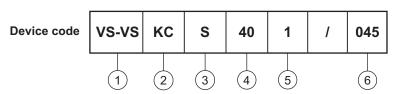
Fig. 8 - Unclamped Inductive Test Circuit

#### Note

 $^{(1)}$  Formula used: T<sub>C</sub> = T<sub>J</sub> - (Pd + Pd<sub>REV</sub>) x R<sub>th,JC</sub>; Pd = Forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 6); Pd<sub>REV</sub> = Inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = 80 % rated V<sub>R</sub>



#### **ORDERING INFORMATION TABLE**



1 - VS-VS = Vishay Semiconductors product

**2** - Circuit configuration:

KC = ADD-A-PAK - 2 diodes/common cathode

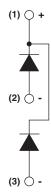
3 - S = Schottky diode

4 - Average rating (x 10)

5 - Product silicon identification

6 - Voltage rating (045 = 45 V)

#### **CIRCUIT CONFIGURATION**

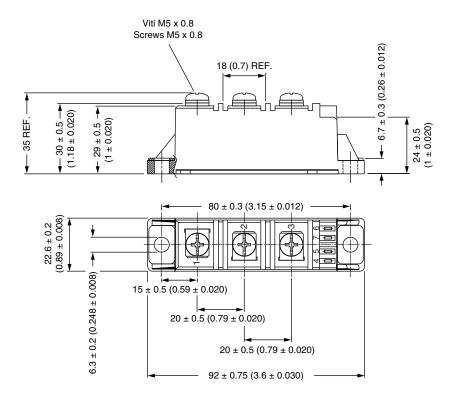


LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95369		



## **ADD-A-PAK Generation VII - Diode**

#### **DIMENSIONS** in millimeters (inches)





## **Legal Disclaimer Notice**

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